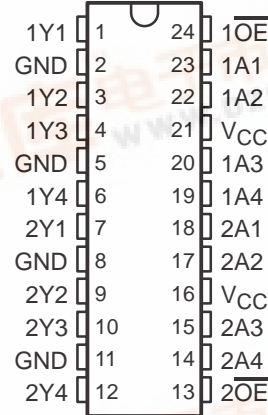PCB   24   **SN64BCT25244**

25-Ω OCTAL BUFFER/DRIVER
WITH 3-STATE OUTPUTS

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- **State-of-the-Art BiCMOS Design Significantly Reduces I_{CCZ}**
- **High-Impedance State During Power Up and Power Down**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **Designed to Facilitate Incident-Wave Switching for Line Impedances of 25 Ω or Greater**
- **Distributed V_{CC} and GND Pins Minimize Noise Generated by the Simultaneous Switching of Outputs**
- **Package Options Include Plastic Small-Outline (DW) Packages and Standard Plastic 300-mil DIPs (NT)**

DW OR NT PACKAGE
(TOP VIEW)

1Y1	1	24	1$\overline{OE}$
GND	2	23	1A1
1Y2	3	22	1A2
1Y3	4	21	V_{CC}
GND	5	20	1A3
1Y4	6	19	1A4
2Y1	7	18	2A1
GND	8	17	2A2
2Y2	9	16	V_{CC}
2Y3	10	15	2A3
GND	11	14	2A4
2Y4	12	13	2$\overline{OE}$

description

The SN64BCT25244 is a 25-Ω octal buffer and line driver designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented transceivers.

When the output-enable (1$\overline{OE}$ and 2$\overline{OE}$) inputs are low, the device transmits data from the A inputs to the Y outputs. When 1$\overline{OE}$ and 2$\overline{OE}$ are high, the outputs are in the high-impedance state.

This buffer/driver is capable of sinking 188-mA I_{OL}, which facilitates switching 25-Ω transmission lines on the incident wave. The distributed V_{CC} and GND pins minimize switching noise for more reliable system operation.

The outputs are in a high-impedance state during power up and power down while the supply voltage value is less than approximately 3 V.

The SN64BCT25244 is characterized for operation from −40°C to 85°C and 0°C to 70°C.

FUNCTION TABLE
(each buffer/driver)

INPUTS		OUTPUT
$\overline{OE}$	A	Y
L	H	H
L	L	L
H	X	Z

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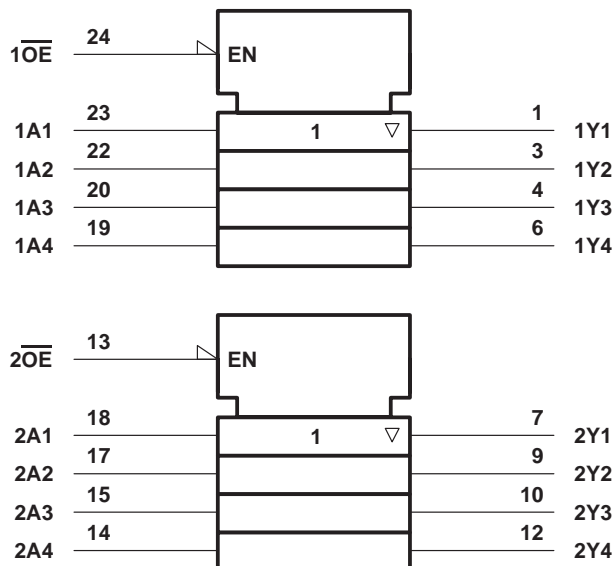
TEXAS INSTRUMENTS

SN64BCT25244
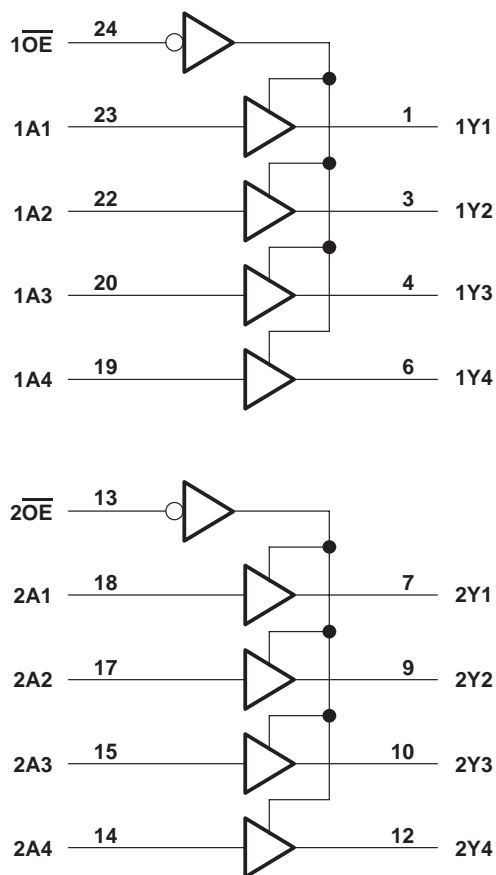## 25-Ω OCTAL BUFFER/DRIVER
WITH 3-STATE OUTPUTS

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logic symbol†

† This symbol is in accordance with ANSI/IEEE Std 91-1984
and IEC Publication 617-12.

logic diagram (positive logic)

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V_{CC} .... −0.5 V to 7 V
Input voltage range, V_I (see Note 1) .... −0.5 V to 7 V
Voltage range applied to any output in the disabled or power-off state, V_O .... −0.5 V to 5.5 V
Voltage range applied to any output in the high state, V_O .... −0.5 V to V_{CC}
Input clamp current, I_{IK} (V_I < 0) .... −30 mA
Current into any output in the low state, I_O .... 376 mA
Operating free-air temperature range .... −40°C to 85°C
Storage temperature range .... −65°C to 150°C

‡ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and
functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not
implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1:   The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	4.5	5	5.5	V
V_{IH}	High-level input voltage	2			V
V_{IL}	Low-level input voltage			0.8	V
I_{IK}	Input clamp current			−18	mA
I_{OH}	High-level output current			−80	mA
I_{OL}	Low-level output current			188	mA
T_A	Operating free-air temperature	−40		85	°C

NOTE 2:   Unused or floating inputs must be held high or low.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{IK}	V_{CC} = 4.5 V,	I_I = −18 mA			−1.2	V
V_{OH}	V_{CC} = 4.75 V,	I_{OH} = − 3 mA	2.7			V
	V_{CC} = 4.5 V,	I_{OH} = −80 mA	2			
V_{OL}	V_{CC} = 4.5 V	I_{OL} = 94 mA		0.42	0.55	V
		I_{OL} = 188 mA			0.7	
I_{OZ}	V_{CC} = 0 to 2.3 V (power up)	V_O = 2.7 V or 0.5 V, $\overline{OE}$ at 0.8 V			±50	μA
	V_{CC} = 2.3 to 0 (power down)				±50	
I_I	V_{CC} = 5.5 V,	V_I = 5.5 V			0.1	mA
I_{IH}	V_{CC} = 5.5 V,	V_I = 2.7 V			20	μA
I_{IL}	V_{CC} = 5.5 V,	V_I = 0.5 V			−0.6	mA
I_{OZH}	V_{CC} = 5.5 V,	V_O = 2.7 V			50	μA
I_{OZL}	V_{CC} = 5.5 V,	V_O = 0.5 V			−50	μA
I_{CCL}	V_{CC} = 5.5 V,	Outputs open		90	119	mA
I_{CCH}	V_{CC} = 5.5 V,	Outputs open		59	78	mA
I_{CCZ}	V_{CC} = 5.5 V,	Outputs open		7	11	mA
C_i	V_{CC} = 5 V,	V_I = 2.5 V or 0.5 V		5.5		pF
C_o	V_{CC} = 5 V,	V_O = 2.5 V or 0.5 V		17		pF

† All typical values are at V_{CC} = 5 V, T_A = 25°C.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Note 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 5 V, T_A = 25°C			T_A = −40°C to 85°C		T_A = 0°C to 70°C		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	Y	1	3.2	4.9	1	5.6	1	5.5	ns
t_{PHL}			2	4	5.6	2	6.3	2	6	
t_{PZH}	$\overline{OE}$	Y	3.2	5.6	8.5	3.2	9.7	3.2	9.3	ns
t_{PZL}			3.7	6.3	9.2	3.7	10.4	3.7	10.2	
t_{PHZ}	$\overline{OE}$	Y	1.6	3.6	5.5	1.6	6.5	1.6	6.3	ns
t_{PLZ}			3.1	5.3	7.8	3.1	9.5	3.1	8.4	

NOTE 3:   Load circuits and voltage waveforms are shown in Section 1.

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